<u>4.6 Small-Signal</u>

Operation and Models

Reading Assignment: pp. 287-294

Recall the **small-signal analysis** we performed on a junction diode.

We can do a similar analysis on MOSFET amplifiers in order to determine their **small-signal gain** !

Remember there were essentially three steps:

HO: Small-Signal Response of MOSFET Circuits

HO: Small-Signal Output Resistance

2.

1.

HO: The MOSFET Small-Signal Model

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Remember there were essentially three steps:

1. Determine the small-signal device equation(s).

HO: Small-Signal Response of MOSFET Circuits

HO: Small-Signal Output Resistance

2. From the small-circuit device equations, determine a small-signal model.

HO: The MOSFET Small-Signal Model

3.

HO: Steps for Small-Signal Analysis

Example: A Small-Signal Analysis of a MOSFET Amp

Example: Another Small-Signal Analysis of a MOSFET Amp

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3. Use the small-signal model to perform a small-signal analysis.

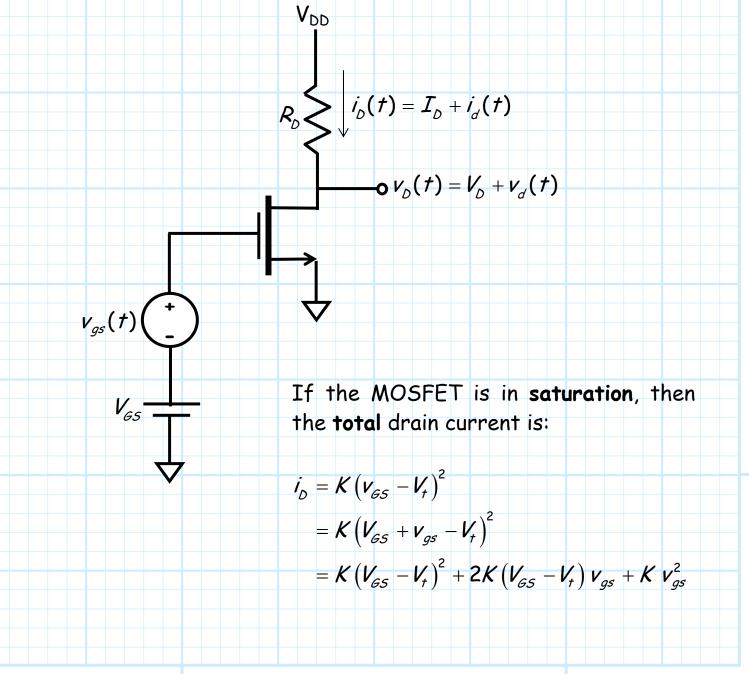
HO: Steps for Small-Signal Analysis

Example: A Small-Signal Analysis of a MOSFET Amp

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<u>Small-Signal Response of</u> <u>MOSFET Circuits</u>

Consider this circuit, which has both a **DC** and an AC **small-signal** source. As a result, each voltage and current in the circuit has **both** a DC and small-signal component.



By looking at this equation, we find that the **third** term is **small** in comparison to the second **if**:

$$v_{gs} \ll 2(V_{GS} - V_{t})$$

We call this equation the **small-signal** condition. For this case, we find that the drain current is:

$$i_{D}(t) = I_{D} + i_{d}(t)$$

$$\approx K \left(V_{GS} - V_{t} \right)^{2} + 2K \left(V_{GS} - V_{t} \right) V_{gS}(t)$$

Thus, it is evident that the **DC** equation is:

 $\boldsymbol{I}_{\mathcal{D}} = \boldsymbol{K} \left(\boldsymbol{V}_{\mathcal{GS}} - \boldsymbol{V}_{\mathcal{T}} \right)^2$

while the small signal equation is:

$$\dot{V}_{d}(t) = 2K(V_{GS} - V_{t})V_{gS}(t)$$

Thus, we can define the MOSFET transconductance as:

$$g_m \doteq \frac{\dot{I}_d}{V_{qs}} = 2K \left(V_{GS} - V_t \right)$$

Note this small-signal parameter g_m can likewise be **derived** from a small-signal analysis of the drain current:

$$i_{d}(t) = \frac{d i_{D}}{dv_{GS}} \bigg|_{v_{GS} = V_{GS}} v_{gs}(t)$$

= $2K (v_{GS} - V_{t}) \bigg|_{v_{GS} = V_{GS}} v_{gs}(t)$
= $2K (V_{GS} - V_{t}) v_{gs}(t)$
= $g_{m} v_{gs}(t)$

The MOSFET transconductance relates a small **change** in v_{GS} to a small **change** in drain current i_D . This change is completely dependent on the **DC** bias point of the MOSFET, V_{GS} and I_D .

We can likewise determine the small signal voltage $v_{ds}(t)$. Writing the KVL for the drain-source leg, we find:

$$V_{DD} - R_D i_D = V_{DS}$$
$$V_{DD} - R_D (I_D + i_d) = V_{DS} + V_{dS}$$
$$V_{DD} - R_D I_D - R_D i_d = V_{DS} + V_{dS}$$

The **DC** equation is therefore:

$$V_{DD} - R_D I_D = V_{DS}$$

while the **small-signal** equation is:

$$-R_{D}i_{d}(t)=v_{ds}(t)$$

Since
$$i_d(t) = g_m v_{gs}(t)$$
, we find that the small-signal voltage $v_{ds}(t)$ is related to $v_{gs}(t)$ as:

$$v_{ds}(t) = -R_D i_d(t)$$
$$= -R_D g_m v_{gs}(t)$$

or:

$$\frac{v_{ds}(t)}{v_{gs}(t)} = -R_D g_m$$

Thus, if $R_D g_m \gg 1$, we have small-signal voltage gain.

<u>MOSFET Output</u> <u>Resistanc</u>e

Recall that due to channel-length modulation, the MOSFET drain current is slightly dependent on v_{DS} , and thus is more accurately described as:

$$\dot{I}_{D} = \mathcal{K} \left(\mathcal{V}_{GS} - \mathcal{V}_{\tau} \right)^{2} \left(1 + \lambda \, \mathcal{V}_{DS} \right)$$

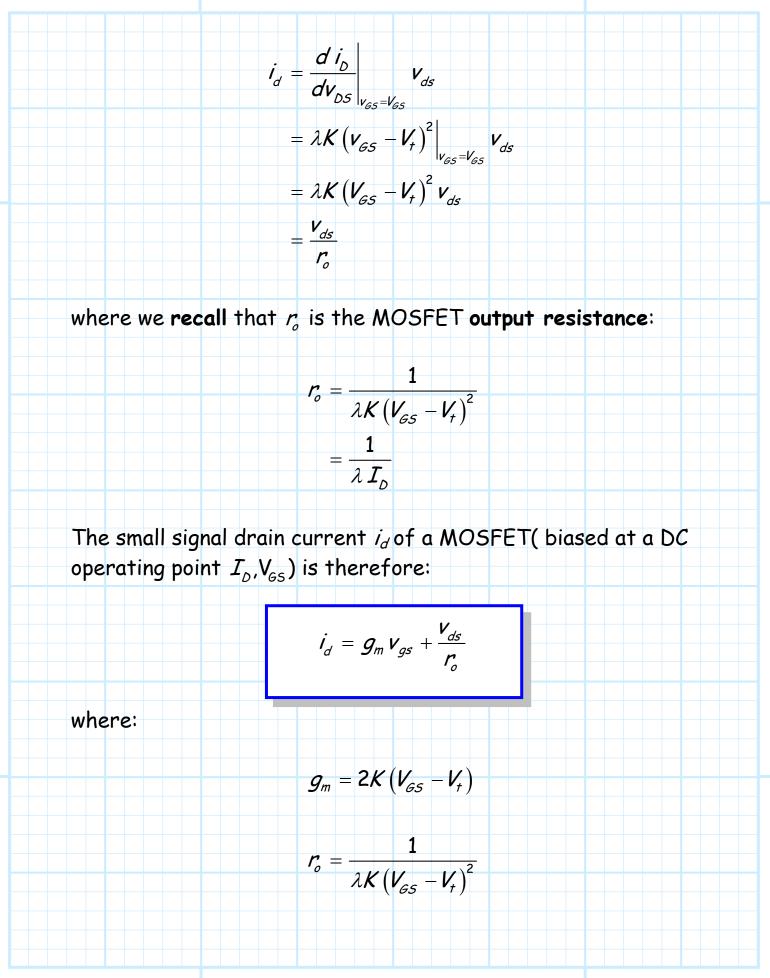
In order to determine the relationship between the small-signal voltage v_{gs} and small-signal current i_d we can apply a small-signal analysis of this equation:

$$\begin{aligned} d &= \frac{d'i_{D}}{d'v_{GS}} \bigg|_{v_{GS}=V_{GS}} v_{gS} \\ &= 2K \left(v_{GS} - V_{t} \right) \bigg|_{v_{GS}=V_{GS}} v_{gS} \\ &= 2K \left(V_{GS} - V_{t} \right) \bigg|_{v_{gS}} \\ &= g_{m} v_{gS} \end{aligned}$$

Note that we evaluated the derivative at the DC bias point V_{GS} . The result, as we expected, was the **transconductance** g_m .

We can likewise determine the relationship between small-signal voltage v_{ds} and the small-signal current i_d :

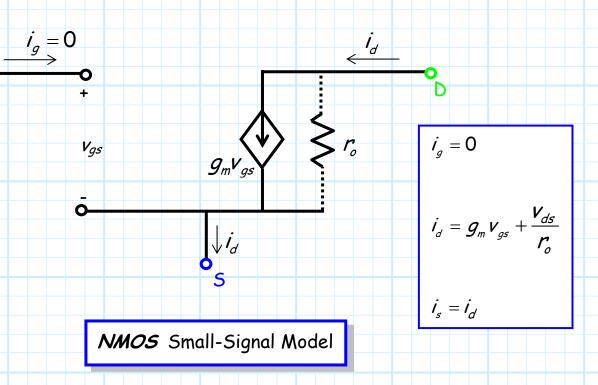




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<u>The MOSFET</u> <u>Small-Signal Model</u>

To determine the small-signal performance of a given MOSFET amplifier circuit, we can replace the MOSFET with its **small-signal model**:



Note that this circuit provides **precisely** the same circuit equations as did our small-signal MOSFET analysis.

<u>MOSFET Small-Signal</u>

<u>Analysis Steps</u>

Complete **each** of these steps if you **choose** to correctly complete a MOSFET Amplifier **small-signal** analysis.

<u>Step 1</u>: Complete a D.C. Analysis

Turn off all small-signal sources, and then complete a circuit analysis with the remaining D.C. sources only.

* Complete this DC analysis exactly, precisely, the same way you performed the DC analysis in section 4.3. That is, you assume (the **saturation** mode), enforce, analyze, and **check (do not forget to check!)**.

* Note that you enforce and check exactly, precisely the same the same equalities and inequalities as discussed in section 4.3.

* Remember, if we "turn off" a voltage source $(e.g.,v_i(t) = 0)$, it becomes a short circuit.

However, if we "turn off" a current source (e.g., i_i(t) = 0), it becomes an open circuit! * Small-signal amplifiers frequently employ large capacitors. Remember, the impedance of a capacitor at DC is infinity—a DC open circuit.

The goal of this DC analysis is to determine:

1) The DC voltage V_{GS} for each MOSFET.

2) The DC voltage V_{DS} for each MOSFET (you need this value for the CHECK).

You do not **necessarily** need to determine any other DC currents or voltages within the amplifier circuit!

Once you have found these values, you can **CHECK** your active assumption, and then move on to **step 2**.

<u>Step 2:</u> Calculate the small-signal circuit parameters for each MOSFET.

Recall that we now understand 2 MOSFET small-signal parameters:

$$g_m = 2K(V_{GS} - V_t) \qquad r_o = \frac{1}{\lambda K(V_{GS} - V_t)^2}$$

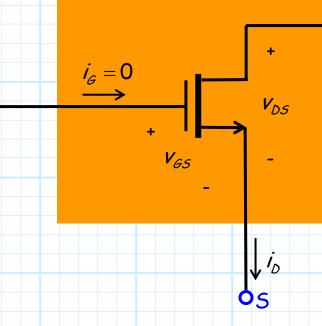
<u>Step 3:</u> Carefully replace all MOSFETs with their **small-signal** circuit model.

This step often gives students fits!

However, it is actually a **very simple** and straight-forward step. It does require four important things from the student **patience**, **precision**, **persistence** and **professionalism**!

First, note that a **MOSFET** is:

A device with **three** terminals, called the gate, drain, and source. Its behavior is described in terms of current i_D and voltages v_{GS} , v_{DS} .



Now, **contrast** the MOSFET with its small-signal circuit model. A MOSFET small-signal circuit model is:

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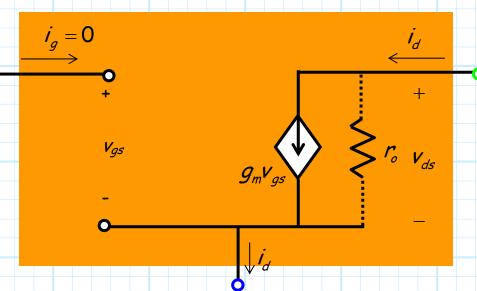
1_D

0

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A device with **three** terminals, called the gate, drain, and source. Its behavior is described in terms of current i_d and voltages v_{qs} , v_{ds} .

Exactly the same—what a coincidence!



Therefore, replacing a MOSFET with its small-signal circuit model is very simple—you simply change the stuff **within** the orange box!

Note the parts of the circuit **external** to the orange box do not change! In other words:

1) every device attached to the MOSFET terminals (i.e, gate, drain, source) is attached in precisely the same way to the terminals of the circuit model.

D

2) every external voltage or current (e.g., v_i , v_o , i_R) is defined in **precisely** the same way both before and after the MOSFET is replaced with its circuit model is (e.g., if the output voltage is the drain voltage in the MOSFET circuit, then the output voltage is **still** the drain voltage in the small-signal circuit!).

Step 4: Set all D.C. sources to zero.

Remember:

A zero voltage DC source is a short.

A zero current DC source is an open.

The schematic in now in front of you is called the small-signal circuit. Note that it is missing two things—DC sources and MOSFET transistors!

* Note that steps three and four are **reversible**. You could turn off the DC sources **first**, and then replace all MOSFETs with their small-signal models—the resulting small-signal circuit will be the **same**!

* You will find that the small-signal circuit schematic can often be greatly **simplified**. Once the DC voltage sources are turned **off**, you will find that the terminals of many devices are connected to **ground**.

* Remember, all terminals connected to ground are **also** connected to each other! For **example**, if the source terminal is connected to ground, and one terminal of a resistor is connected to ground, then that resistor terminal is connected to the source!

* As a result, you often find that resistors in different parts of the circuit are actually connected in **parallel**, and thus can be **combined** to simplify the circuit schematic!

* Finally, note that the AC impedance of a very large capacitor (i.e., $|Z_c| = 1/\omega C$) is small for all but the lowest frequencies ω . If this impedance is smaller than the other circuit elements (e.g., < 10 Ω), we can view the impedance as approximately zero, and thus replace the large capacitor with a (AC) short!

Organizing and **simplifying** the small-signal circuit will pay **big** rewards in the next step, when we **analyze** the small-signal circuit.

Step 5: Analyze small-signal circuit.

We now can **analyze** the small-signal **circuit** to find all smallsignal **voltages** and **currents**.

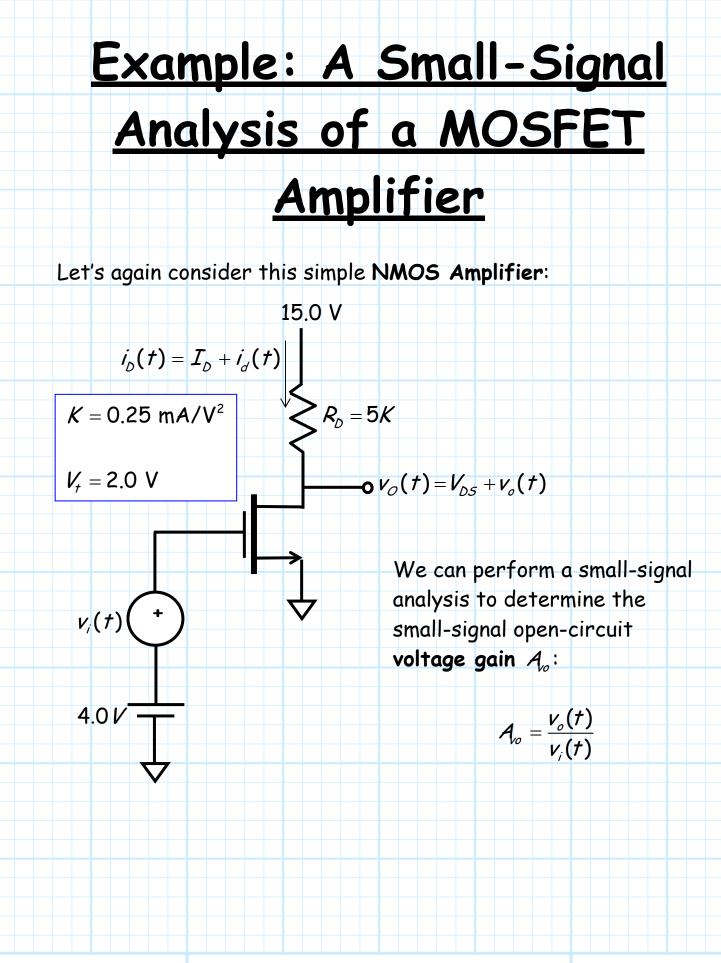
* For small-signal **amplifiers**, we typically attempt to find the small-signal output voltage v_o in terms of the smallsignal input voltage v_i . From this result, we can find the **voltage gain** of the amplifier.

* Note that this analysis requires **only** the knowledge you acquired in **EECS 211**! The small-signal circuit will consist **entirely** of resistors and (small-signal) voltage/current sources. These are **precisely** the same resistors and sources that you learned about in EECS 211. You analyze them in **precisely** the same way.

* Do **not** attempt to insert any MOSFET knowledge into your small-signal circuit analysis—there are **no** MOSFETs in a small-signal circuit!!!!!

* Remember, the MOSFET circuit model contains **all** of our MOSFET small-signal knowledge, we **do** not—indeed **must** not—add any more information to the analysis.

You must **trust** completely the MOSFET small-signal circuit model. It **will** give you the correct answer!



15.0 V

 I_{D}

 oV_{DS}

 $R_D = 5K <$

4.0*V*

Step 1: DC Analysis

Turning off the small signal source leaves a DC circuit of:

We ASSUME saturation, so that we ENFORCE:

$$\boldsymbol{I}_{D} = \boldsymbol{K} \left(\boldsymbol{V}_{GS} - \boldsymbol{V}_{t} \right)^{2}$$

It is evident that:

$$V_{GS} = 4.0 V$$

Therefore the DC drain current is:

 $I_{D} = K (V_{GS} - V_{t})^{2}$ = 0.25(4 - 2)^{2} = 1.0 mA

Thus, the DC voltage V_{DS} can be determined from KVL as:

$$V_{DS} = 15.0 - I_D R_D$$

= 15.0 - 1(5)
= 10.0 V

We CHECK our results and find:

$$V_{GS} = 4.0 > V_{t} = 2.0$$

Jim Stiles

 $V_{DS} = 10.0 > V_{GS} - V_{f} = 2.0$

and:

Step 2: Determine the small-signal parameters

We find that the **transconductance** is:

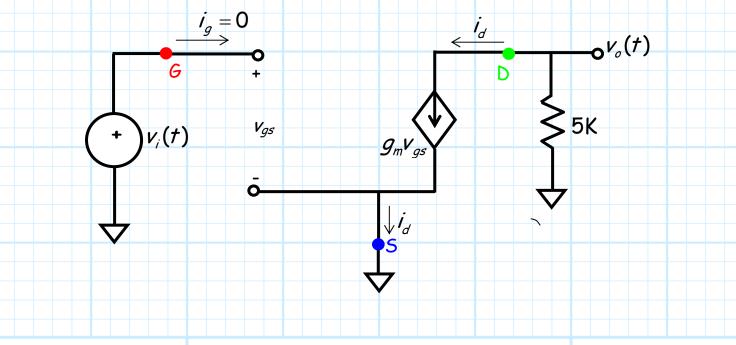
$$g_{m} = 2K(V_{GS} - V_{t})$$

= 2(0.25)(4.0 - 2.0)
= 1 mA/V

Note that no value of λ was given, so we will assume $\lambda = 0$, and thus output resistance $r_o = \infty$.

Steps 3 and 4: Determine the small-signal circuit

We now turn off the **two** DC voltage source, and replace the MOSFET with its **small signal model**. The result is our **small-signal circuit**:



Step 5: Analyze the small-signal circuit

The analysis of this small-signal circuit is fairly **straightforward**. First, we note that:

 $V_{gs} = V_i$

and that:

$$\dot{y}_d = g_m v_{gs}$$

= 1.0 v_{gs}
= v_{gs}

and that:

 $v_o = -5 i_d$

Combing these equations, we find that:

$$v_o = -5 v_i$$

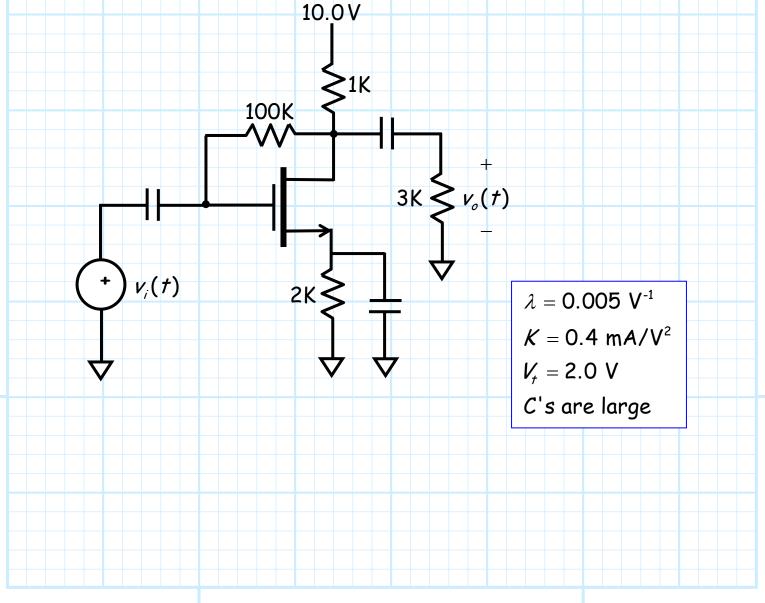
And thus the **small-signal** open-circuit voltage gain of this amplifier is:

$$\mathcal{A}_{v_o} = \frac{v_o(t)}{v_i(t)} = -5.0$$

Jim Stiles

<u>Example: Another Small-</u> <u>Signal Analysis of a</u> <u>MOSFET Amplifier</u>

Let's determine the small-signal voltage gain $A_i = v_o/v_i$ (note not the open-circuit gain!) of the following amplifier:



10.0V

100K

V_{GS}

╋

•1K

 I_{D}

 V_{DS}

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Step 1: DC Analysis

Capacitors are **open** circuits at DC, therefore the DC circuit is:

We ASSUME the MOSFET is in saturation, thus we ENFORCE:

$$\mathcal{I}_{\mathcal{D}} = \mathcal{K} \left(\mathcal{V}_{\mathcal{GS}} - \mathcal{V}_{\mathcal{T}} \right)^2$$

Since $I_G = 0$, we find that $V_G = V_D$, and thus $V_{GS} = V_{DS}$. From KVL, we find:

$$10.0 - (1) I_D - V_{DS} - (2) I_D = 0$$

Or since $V_{GS} = V_{DS}$:

$$V_{GS} = 10.0 - 3I_D$$

Combining this with $I_D = K (V_{GS} - V_t)^2$, we get a **quadratic** equation of V_{GS} :

$$V_{GS} = 10.0 - 3K \left(V_{GS} - V_{t} \right)^{2}$$

The solutions to this equation are:

$$V_{GS} = 4.2 \text{ V}$$
 and $V_{GS} = -1.0 \text{ V}$

Don't panic! Only one of these solutions satisfy our saturation assumption: $V_{GS} = 4.2 > 2.0 = V_{t}$.

